### **Application Data Sheet**

#### **Inventor Information**

Inventor One Given Name:

Family Name:

Name Suffix:

Postal Address Line One Postal Address Line Two

City:

State or Province:

Postal or Zip Code:

Citizenship Country:

Inventor Two Given Name:

Family Name: Name Suffix:

Postal Address Line One Postal Address Line Two

City:

State or Province: Postal or Zip Code: Citizenship Country: Tetsuyoshi

**INOUE** 

2-3-52-109, Nishimikurado

Yamatotakada-shi Nara-ken, Japan

Japan

Kazunori **MATSUBARA** 

537, Yakuoii. Tawaramoto-cho,

Shiki-gun

Nara-ken, Japan

## **Correspondence Information**

Name Line One:

Name Line Two:

Address Line One:

Address Line Two:

City:

State or Province:

Postal or Zip Code:

Telephone: Fax:

Electronic Mail:

Barry E. Bretschneider Morrison & Foerster LLP

2000 Pennsylvania Avenue, N.W.

Suite 5500

Washington

DC

20006-1888 (202) 887-1545 (202) 263-8396

BBretschneider@mofo.com

# **Application Information**

Title Line One:

Title Line Two:

**Total Drawing Sheets:** Formal Drawing Application Type:

Docket Number:

SEMICONDUCTOR LASER MANUFACTURING METHOD AND SEMICONDUCTOR LASER

7 Yes

Utility

204552021700

# Representative Information

Representative Customer Number: 25227

# **Prior Foreign Applications**

Foreign Application One:

Filing Date:

Country:
Priority Claimed:

2000-354191

November 21, 2000

Japan

Yes